HD31993
SOLID STATE HIGH POWER AMPLIFIER

HD Communications Corp.

FEATURES

Small and light weight bench-top chassis
Class AB linear GaAsFET hybrid design
Instantaneous wide bandwidth
Designed for EMC-EMI/RFI, Lab, and general communication applications
Suitable for all single channel modulation standards
Built-in protection circuits
High reliability and ruggedness



ELECTRICAL SPECIFICATIONS: 50Ω, 25°C

Parameter	Specification	Notes
Operating Frequency Range	26.5 - 40.0 GHz	
Power Output	5 Watt Typ	Saturated CW
Power output at P1dB GCP	3 Watt Typ	
Power Gain	37 dB Min	
Power Gain Flatness	6.0 dB p-p Max	
Input Return Loss	-10 dB Max	Relative to 50 Ohm
Noise Figure	12 dB Max	
Harmonics	<-20 dBc Typ	At rated Pout
Spurious	-60 dBc Max	Non-harmonics
Operating Voltage	100 - 240 VAC	
Power Consumption	90 Watt Max	At rated Pout
Input Power Protection	+3 dBm Max	<10 Seconds without damage
Load VSWR Protection	∞ : 1	<1 Minute at rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Ambient Temperature	0 to +50 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

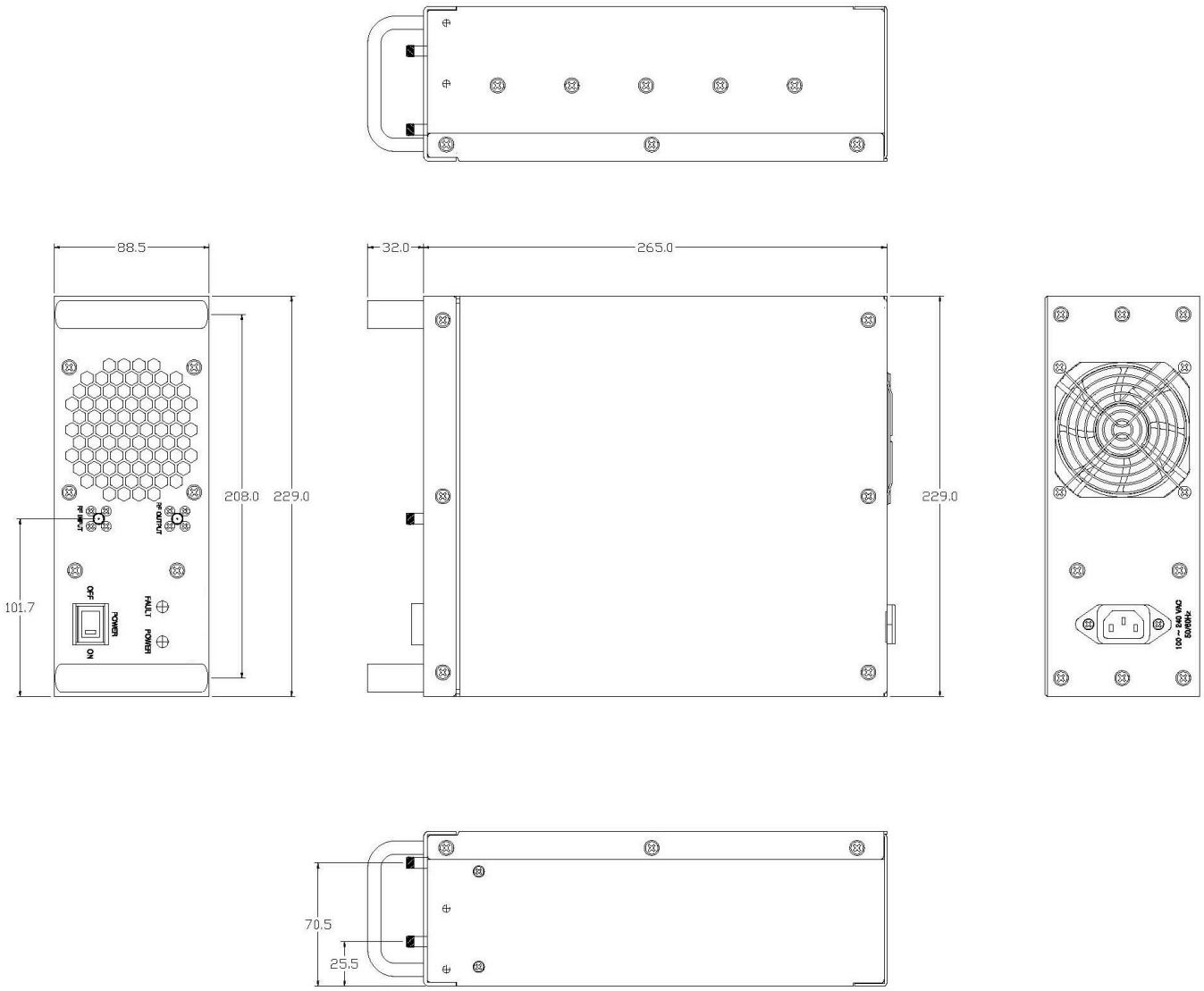
MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions W x H x D	265 x 88 x 229 mm	Bench Top
Weight	8 kg.	
RF Connectors In/Out	2.9 mm (K / air type) Female	Front Panel Standard
AC Power / Interface Connector	IEC 60320-C14 / 9-Pin D-Sub	
Cooling	Built in Fan Cooling	
OPTIONAL: Digital Monitor & Control FWD, REV, VSWR, GAIN, ALC, V & I, TEMP	Ethernet RJ-45 TCP/IP, USB, RS422/485 Optional GPIB Interface	LCD available in a 2U Chassis

332C Dante Ct. Holbrook, NY 11741 Phone: 631-588-3877 Fax: 631-648-0518
www.rfcomp.com www.rfamplifiers.com sales@hdcom.com

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OUTLINE DRAWING



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